isc N-Channel MOSFET Transistor

BUZ341

FEATURES

- Drain Current : I_D= 33A@ T_C=25 ℃
- Drain Source Voltage
 - : V_{DSS}= 200V(Min)
- Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 0.07 \Omega (Max) @ V_{GS} = 10V$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



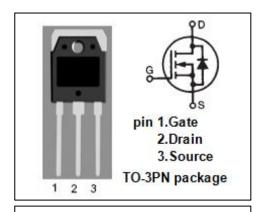
 motor drive, DC-DC converter, power switch and solenoid drive.

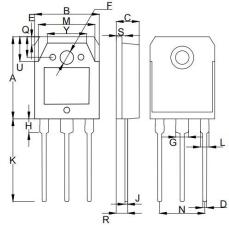
ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	200	V
V _G s	Gate-Source Voltage-Continuous	±20	V
I _D	Drain Current-Continuous	33	А
I _{DM}	Drain Current-Single Pluse	132	А
P _D	Total Dissipation @T _C =25℃	170	W
TJ	Max. Operating Junction Temperature	-55~150	$^{\circ}$
T _{stg}	Storage Temperature	-55~150	$^{\circ}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	0.74	°C/W





DIM	m	nm
DIIVI	MIN	MAX
Α	19.60	20.30
A B	15.30	15.90
C	4.70	4.90
D	0.90	1.10
E	1.90	2.10
F	3.40	3.60
G	2.90	3.20
Н	3.20	3.40
J	0.595	0.605
K	19.80	20.70
L M	1.90	2.20
M	13.30	13.90
N	10.89	10.91
Q	4.25	5.10
R	3.30	3.45
S	1.995	2.100
U	5.90	6.20
Υ	9.90	10.10

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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA	200		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = 10V; I _D = 1.0mA	2.1	4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 21A		0.07	Ω
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V;V _{DS} = 0		±0.1	uA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 200V; V _{GS} = 0		1.0	uA
Vsp	Forward On-Voltage	I _S = 21A; V _{GS} = 0		1.5	V

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